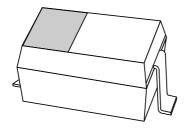
DISCRETE SEMICONDUCTORS

DATA SHEET



PMEG2020AEA

20 V, 2 A very low V_F MEGA Schottky barrier rectifier in SOD323 (SC-76) package

Product specification

2004 Feb 26





20 V, 2 A very low V_F MEGA Schottky barrier rectifier in SOD323 (SC-76) package

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FEATURES

Forward current: 2 AReverse voltage: 20 VVery low forward voltage

· Very small SMD package.

APPLICATIONS

Low voltage rectification

• High efficiency DC/DC conversion

• Switch mode power supply

· Inverse polarity protection

• Low power consumption applications.

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small SMD plastic package.

MARKING

| TYPE NUMBER | MARKING CODE |
|-------------|--------------|
| PMEG2020AEA | S3 |

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | VALUE | UNIT |
|----------------|-----------------|-------|------|
| I _F | forward current | 2 | Α |
| V_R | reverse voltage | 20 | V |

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | cathode |
| 2 | anode |

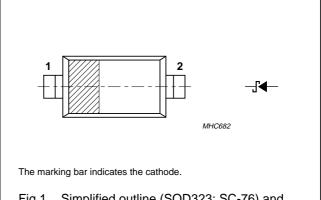


Fig.1 Simplified outline (SOD323; SC-76) and symbol.

RELATED PRODUCTS

| TYPE NUMBER | DESCRIPTION | FEATURES |
|-------------|--|--|
| PMEG1020EA | 2 A; 10 V ultra low V _F MEGA Schottky barrier rectifier | SOD323 package; lower reverse voltage; lower forward voltage |
| PMEG2010EA | 1 A; 20 V ultra low V _F MEGA Schottky barrier rectifier | SOD323 package; lower forward current; lower reverse current and diode capacitance |

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | |
|--------------|--------------------------|--|--------|--|
| I THE NUMBER | NAME DESCRIPTION VERSION | | | |
| PMEG2020AEA | _ | plastic surface mounted package; 2 leads | SOD323 | |

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|--|------|------|------|
| V_R | continuous reverse voltage | | _ | 20 | V |
| I _F | continuous forward current | T _{sp} ≤ 55 °C | _ | 2 | Α |
| I _{FRM} | repetitive peak forward current | $t_p \le 1 \text{ ms}; \delta \le 0.25$ | _ | 7 | Α |
| I _{FSM} | non-repetitive peak forward current | t = 8 ms square wave | _ | 9 | Α |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|--|---------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | notes 1 and 2 | 450 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | notes 2 and 3 | 210 | K/W |
| R _{th(j-s)} | thermal resistance from junction to solder point | note 4 | 90 | K/W |

Notes

- 1. Refer to SOD323 (SC-76) standard mounting conditions.
- 2. For Schottky barrier diodes thermal runaway has to be considered, as in some applications, the reverse power losses P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and I_F (AV) rating will be available on request.
- 3. Device mounted on a on an FR4 printed-circuit board with copper clad 10 x 10 mm.
- 4. Soldering point of cathode tab.

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | TYP. | MAX. | UNIT |
|----------------|-------------------|--|------|------|------|
| V _F | forward voltage | see Fig.2; note 1 | | | |
| | | I _F = 0.01 A | 200 | 220 | mV |
| | | I _F = 0.1 A | 265 | 290 | mV |
| | | I _F = 1 A | 380 | 430 | mV |
| | | I _F = 2 A | 450 | 525 | mV |
| I _R | reverse current | V _R = 5 V; see Fig.3 | 15 | 50 | μΑ |
| | | V _R = 10 V | 20 | 80 | μΑ |
| | | V _R = 20 V | 50 | 200 | μΑ |
| C _d | diode capacitance | V _R = 5 V; f = 1 MHz; see Fig.4 | 55 | 70 | pF |

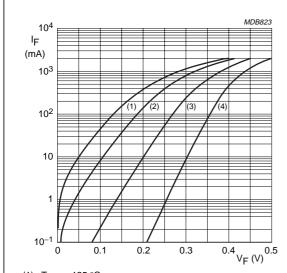
Note

1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

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GRAPHICAL DATA



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \,^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.

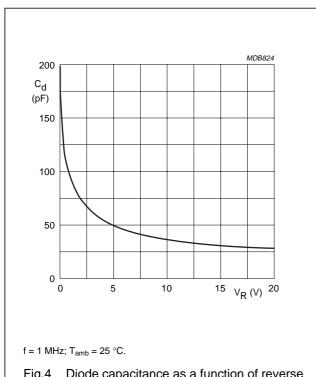
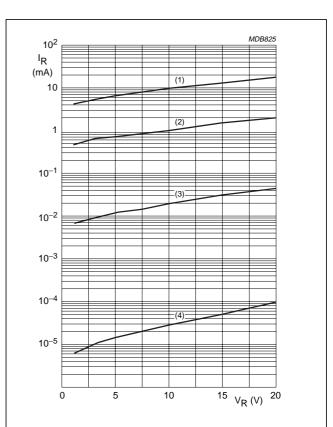


Fig.4 Diode capacitance as a function of reverse voltage; typical values.



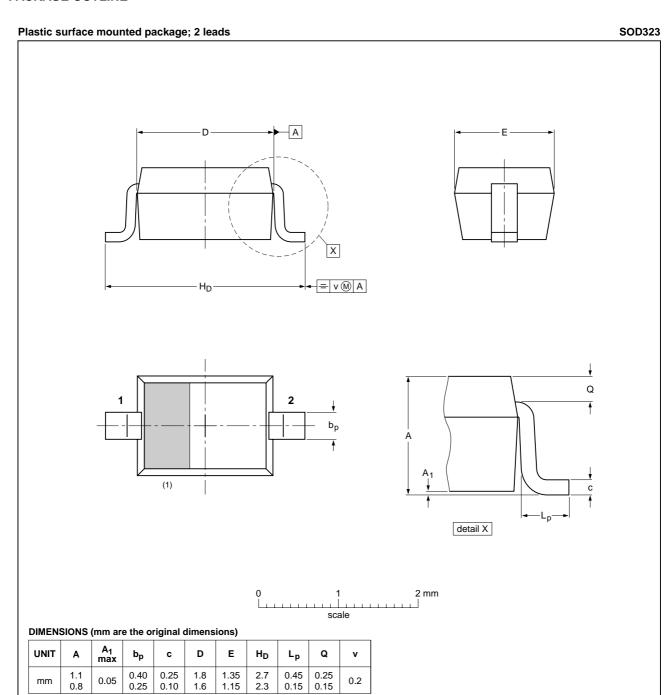
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \,^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.

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PACKAGE OUTLINE



Note

1. The marking bar indicates the cathode

| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|------------|-------|-------|----------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOD323 | | | SC-76 | | | 99-09-13 03-12-17 |

20 V, 2 A very low V_F MEGA Schottky barrier rectifier in SOD323 (SC-76) package

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DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| II | Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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